Applicants: Paul Davids et al.
Serial No.: 10/085,474
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Intel Docket No.: P13240

AMENDMENTS TO THE CLAIMS:

This listing of claims replaces all prior versions and listings of claims in the application:

LISTING OF CLAIMS:

1. (Currently Amended) A waveguide device, comprising:

a waveguide core having a bottom surface and a top surface that defines an angle; and

a cladding layer adjacent to the bottom surface, the cladding layer having a thickness

equal to or greater than an evanescent tail of a mode to be transmitted along the waveguide wave

guide core;

a detector layer, and

an attenuating layer coupled to the bottom surface of the waveguide core and positioned on top of the detector layer;

wherein the mode is transmitted along the waveguide core through the attenuating layer into the detector layer.

- 2. (Currently Amended) The waveguide device of claim 1, wherein the angle is at least equal to an angle of total internal reflection of the waveguide core.
- 3. (Currently Amended) The waveguide device of claim 1, wherein the waveguide core defines a beveled mirror.

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4. (Currently Amended) The waveguide device of claim 1, further comprising:
wherein the detector layer comprises a base of a phototransistor having a base;
wherein the waveguide core is coupled to the base of the phototransistor.

- 5. (Currently Amended) The waveguide device of claim 4, wherein the waveguide core defines a beveled mirror.
- 6. (Currently Amended) The waveguide device of claim 5, wherein the waveguide core is disposed over a substrate and the beveled mirror directs the mode, propagated through the waveguide core, through the detector layer into the substrate.
- 7. (Currently Amended) The waveguide device of claim 1, further comprising:

 wherein the detector layer comprises an intrinsic layer region of a photodiode having an n-type region, an intrinsic layer region, and a p-type region,

wherein the waveguide core is coupled to the intrinsic layer region of the photodiode.

8. (Currently Amended) The waveguide device of claim 7, wherein the waveguide core defines a beveled mirror.

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9. (Currently Amended) The waveguide device of claim 8, wherein the waveguide core is disposed over a substrate and the beveled mirror directs a the mode, propagated through the waveguide core, through the detector layer into the substrate.

Claims 10 to 30 (Cancelled)

31. (New) A device, comprising:

a waveguide core having a bottom surface;

a cladding layer adjacent to the bottom surface, the cladding layer having a thickness equal to or greater than an evanescent tail of a mode to be transmitted along the waveguide core;

a detector layer; and

an attenuating layer coupled to the bottom surface of the waveguide core and positioned on top of the detector layer.

- 32. (New) The device of claim 31, wherein the waveguide core has a top surface that defines an angle, the angle being at least equal to an angle of total internal reflection of the waveguide core.
 - 33. (New) The device of claim 31, wherein the waveguide core defines a beveled mirror.

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34. (New) The device of claim 31, wherein the detector layer comprises a base of a phototransistor.

- 35. (New) The device of claim 34, wherein the waveguide core defines a beveled mirror.
- 36. (New) The device of claim 35, wherein the waveguide core is disposed over a substrate and the beveled mirror directs the mode propagated through the waveguide core and through the detector layer into the substrate.
- 37. (New) The device of claim 31, wherein the detector layer comprises an intrinsic layer region of a photodiode having an n-type region-and a p-type region.
 - 38. (New) The device of claim 37, wherein the waveguide core defines a beveled mirror.
- 39. (New) The device of claim 38, wherein the waveguide core is disposed over a substrate and the beveled mirror directs the mode propagated through the waveguide core and through the detector layer into the substrate.
 - 40. (New) A device, comprising:
 - a waveguide core having a bottom surface;
 - a cladding layer adjacent to the bottom surface;

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a detector layer; and

an attenuating layer coupled to the bottom surface of the waveguide core and positioned on top of the detector layer;

wherein the mode is transmitted along the waveguide core through the attenuating layer into the detector layer.

- 41. (New) The device of claim 40, wherein the waveguide core has a top surface that defines an angle, the angle being at least equal to an angle of total internal reflection of the waveguide core.
 - 42. (New) The device of claim 40, wherein the waveguide core defines a beveled mirror.
- 43. (New) The device of claim 40, wherein the detector layer comprises a base of a phototransistor.
 - 44. (New) The device of claim 43, wherein the waveguide core defines a beveled mirror.
- 45. (New) The device of claim 44, wherein the waveguide core is disposed over a substrate and the beveled mirror directs a mode propagated through the waveguide core through the detector layer into the substrate.

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46. (New) The device of claim 40, wherein the detector layer comprises an intrinsic layer region of a photodiode having an n-type region and a p-type region.

- 47. (New) The device of claim 46, wherein the waveguide core defines a beveled mirror.
- 48. (New) The device of claim 47, wherein the waveguide core is disposed over a substrate and the beveled mirror directs a mode, propagated through the waveguide core, through the detector layer into the substrate.
- 49. (New) The device of claim 40, wherein the cladding layer has a thickness equal to or greater than an evanescent tail of a mode to be transmitted along the waveguide core.
- 50. (New) The device of claim 49, wherein the mode is transmitted along the waveguide core through the attenuating layer into the detector layer.